

Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-15	V
Collector-Emitter Voltage	V_{CEO}	-12	V
Emitter-Base Voltage	V_{EBO}	-6	V
Collector Current - Continuous	Ic	-500	mA
Peak Pulse Collector Current	I _{CM}	-1	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4) @ T _A = 25°C	P _D	150	mW
Thermal Resistance, Junction to Ambient (Note 4) @ T _A = 25°C	$R_{ hetaJA}$	833	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes: 4. Device mounted on FR-4 PCB with minimum recommended pad layout.

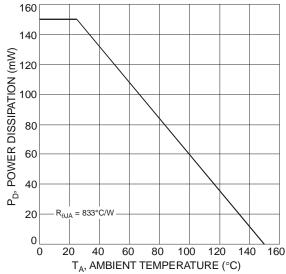


Fig. 1 Power Dissipation vs. Ambient Temperature

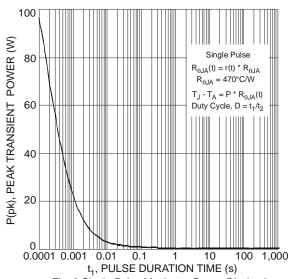


Fig. 2 Single Pulse Maximum Power Dissipation

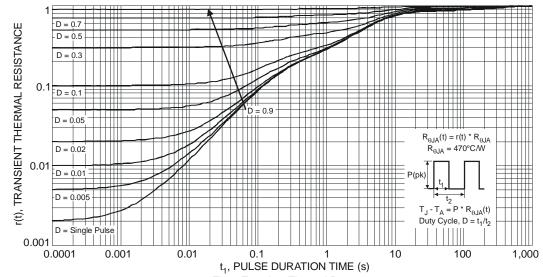


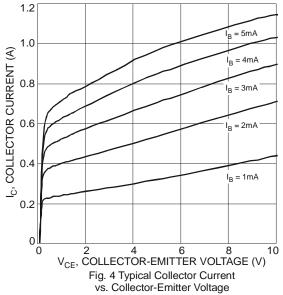
Fig. 3 Transient Thermal Response

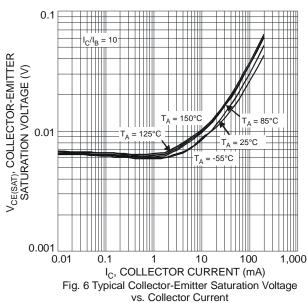


Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-15	_	_	V	$I_C = -10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage (Note 5)	BV _{CEO}	-12	_	_	V	$I_C = -1 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	-6	_	_	V	$I_E = -10\mu A, I_C = 0$
Collector Cutoff Current	I _{CBO}	_	_	-100 -50		$V_{CB} = -15V, I_E = 0$ $V_{CB} = -15V, I_E = 0, T_A = 150$ °C
Emitter Cutoff Current	I _{EBO}	_	_	-100	nA	$V_{EB} = -6V, I_{C} = 0$
DC Current Gain (Note 5)	h _{FE}	270	_	680	_	V _{CE} = -2V, I _C = -10mA
Collector-Emitter Saturation Voltage (Note 5)	V _{CE(sat)}	_	_	-250	mV	$I_C = -200 \text{mA}, I_B = -10 \text{mA}$
Output Capacitance	C _{obo}	_	7.4	_	pF	V _{CB} = -10V, f = 1.0MHz
Current Gain-Bandwidth Product	f⊤	_	260	_	MHz	$V_{CE} = -2V$, $I_{C} = -10$ mA, $f = 100$ MHz
Turn-On Time	t _{on}	_	40	_	ns	
Delay Time	t _d	_	18	_	ns	
Rise Time	t _r	_	22	_	ns	$V_{CC} = -6V$
Turn-Off Time	t _{off}		106		ns	$I_C = -200 \text{mA}, I_{B1} = I_{B2} = -10 \text{mA}$
Storage Time	ts		87		ns	
Fall Time	t _f		19	_	ns	

Notes: 5. Measured under pulsed conditions. Pulse width = 300μ s. Duty cycle \leq 2%.





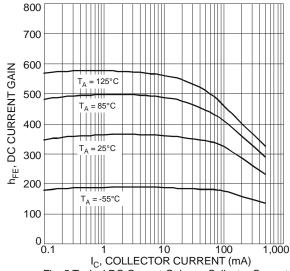
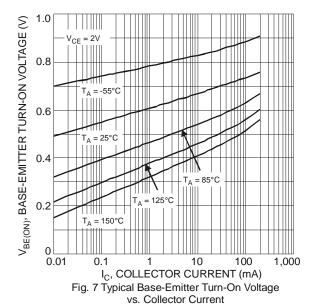
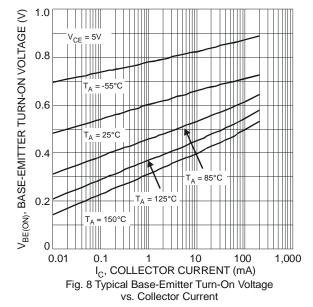
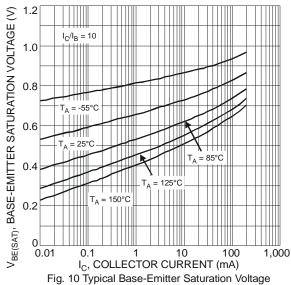


Fig. 5 Typical DC Current Gain vs. Collector Current

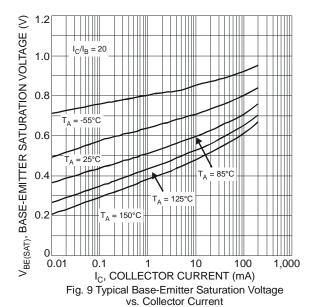


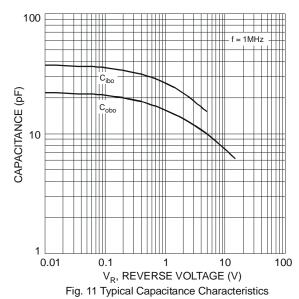




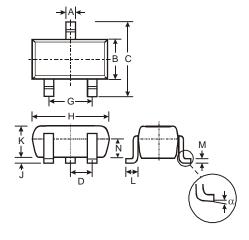


vs. Collector Current





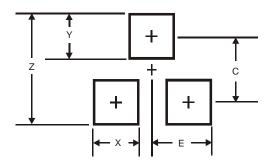
Package Outline Dimensions



SOT-523				
Dim	Min	Max	Тур	
Α	0.15	0.30	0.22	
В	0.75	0.85	0.80	
С	1.45	1.75	1.60	
D	_	_	0.50	
G	0.90	1.10	1.00	
Н	1.50	1.70	1.60	
J	0.00	0.10	0.05	
K	0.60	0.80	0.75	
L	0.10	0.30	0.22	
M	0.10	0.20	0.12	
N	0.45	0.65	0.50	
α	0°	8°		
All Dimensions in mm				



Suggested Pad Layout



Dimensions	Value (in mm)
Z	1.8
Х	0.4
Υ	0.51
С	1.3
E	0.7

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